

# Organic electronics: case studies in commercialization

J. Campbell Scott

IBM Almaden Research Center, San Jose CA

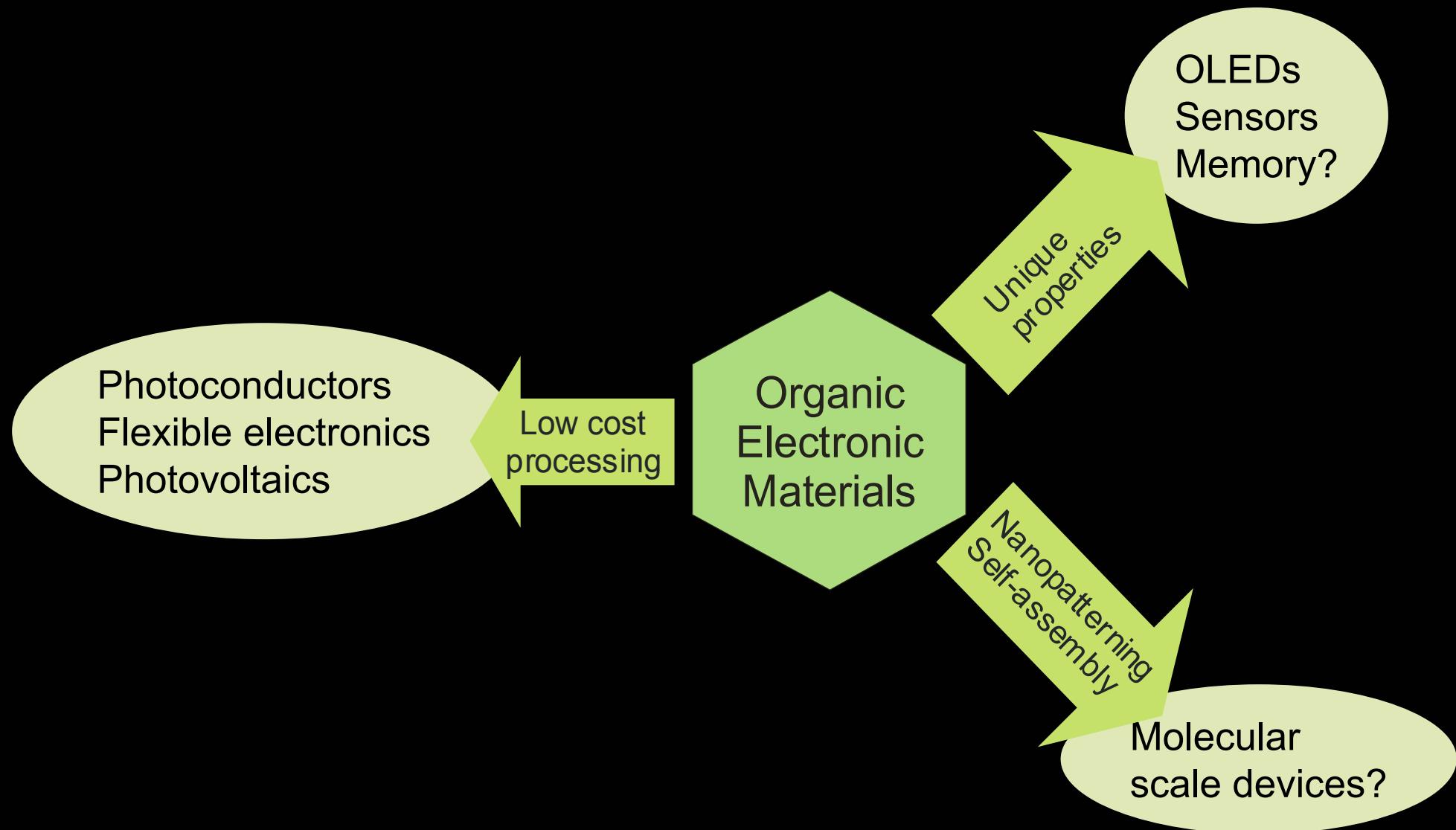
[jcscott@almaden.ibm.com](mailto:jcscott@almaden.ibm.com)

1-408-927-1150

## Outline

1. Organic photoconductors – an historical perspective
2. Organic light-emitting diodes  
– the view from within a large company
3. Nanotrap memory – a new application?

# Applications of Organic and Molecular Electronics



# Organic Photoconductors – since 1966

## United States Patent Office

**3,484,237**

**Patented Dec. 16, 1969**

**1**

**3,484,237**

### **ORGANIC PHOTOCOndUCTIVE COMPOSITIONS AND THEIR USE IN ELECTROPHOTOGRAPHIC PROCESSES**

Meredith D. Shattuck and Ulo Vahtra, San Jose, Calif.,  
assignors to International Business Machines Corporation,  
Armonk, N.Y., a corporation of New York

Filed June 13, 1966, Ser. No. 556,982

Int. Cl. G03g 7/00

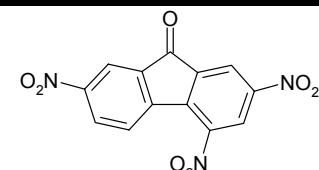
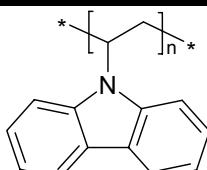
**U.S. CL. 96—1.5**

**8 Claims**

### **ABSTRACT OF THE DISCLOSURE**

An organic photoconductive composition comprising from about 0.49 to about 1.23 moles of 2,4,7-trinitro-9-fluorenone per monomeric unit of a polymerized vinyl-carbazole compound.

**PVK-TNF**



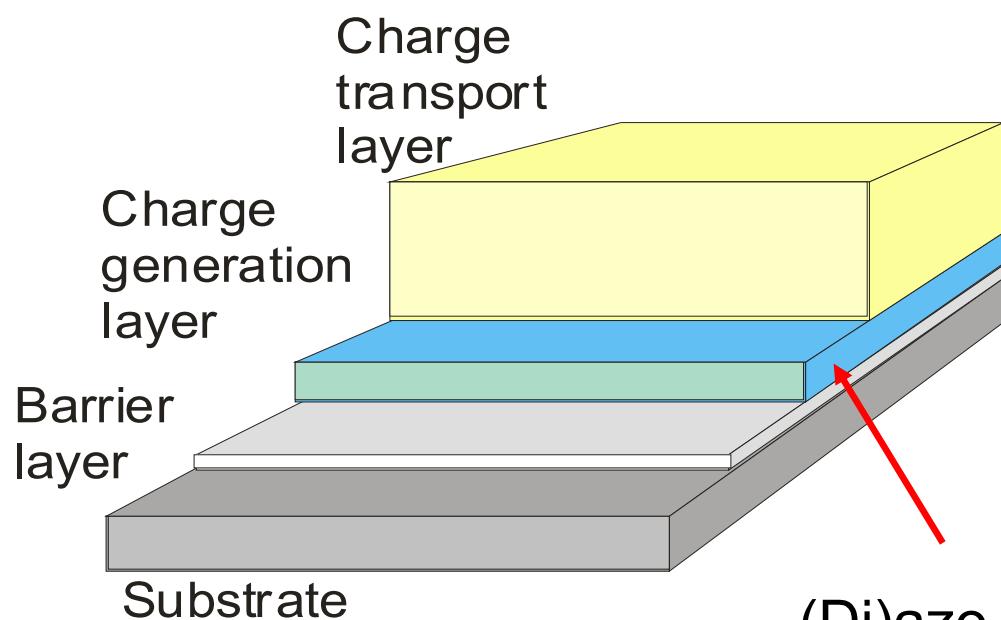
**2**

the dark conductivity to become too high and the photoconductive composition will no longer accept sufficient electrostatic charge to be useful in electrophotography.

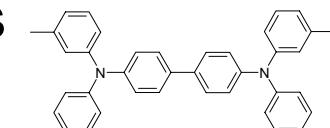
Because of the combination of lack of stability and low sensitivity, organic photoconductive compositions have been competitively unfit for use in a high speed optical xerographic copier in which the photoconductor is reused thousands of times. That is, the known organic photoconductive compositions have not compared favorably with the sensitivity or exposure speed and stability of commercial selenium presently being used in xerographic copiers. To be competitive with selenium, an organic photoconductive composition has to have a sensitivity or exposure speed not less than two times slower than the exposure speed of selenium.

It has now been discovered that organic photoconductive compositions, comprising from about 0.49 to about 1.23 moles of 2,4,7-trinitro-9-fluorenone, are useful.

# Materials for Organic Photoconductors

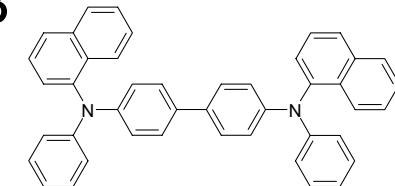


Arylamines

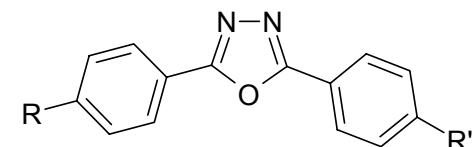


TPD

NPB



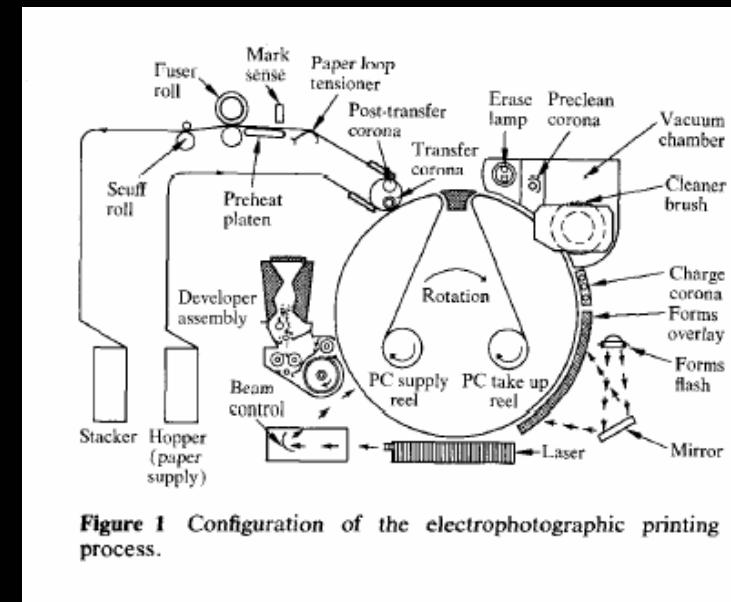
Oxadiazoles



(Di)azo-dyes  
Squarilium derivs.  
Phthalocyanines

# A brief history of OPC

- Original motivation (1965)
  - Circumvent Xerox Se patent
- Ultimate drivers (Canon 1984)
  - Cost, reduced toxicity, spectral sensitivity (840nm)
- Original format
  - Web, reel-to-reel coating
- Ultimate format
  - Drum, dip-coating



Vahtra and Wolter  
IBM J. Res. Dev. 1978

From AEG website



## Lessons from OPC

Trickles flow both down and up

Organics started at high end (no low end EP)

... helped to create low end

... took over all but the very top

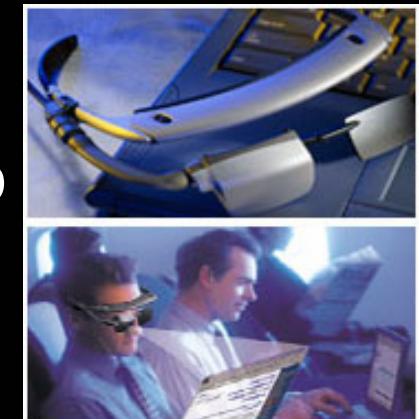
Materials optimized after application is identified

# Organic light-emitting diodes

- Motivation (in a large computer company)
  - Provide an alternative to liquid-crystal flat-panel display (for laptop computers)
  - More efficient (battery life in mobile devices)
  - Better viewing angle
  - Thinner, lighter
  - Enable new applications, e.g. head-mount, virtual 3D

- Issues addressed

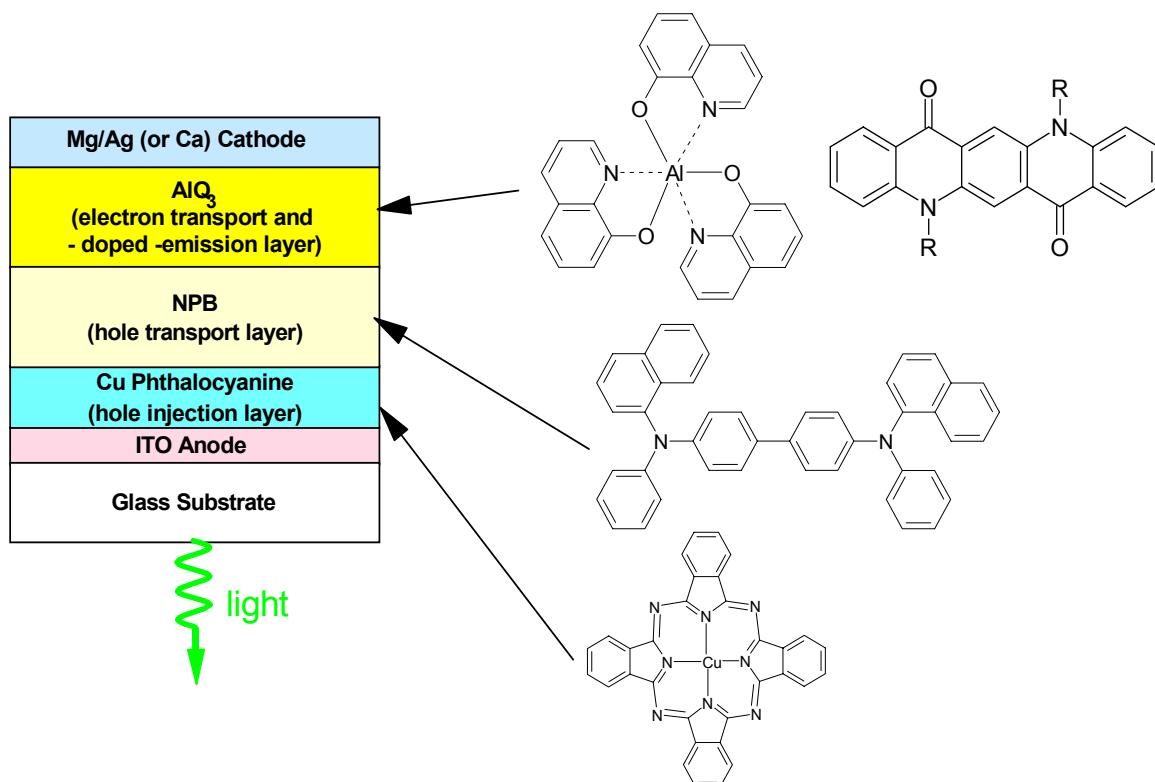
- Lifetime
- Color gamut
- Driver electronics
- Processing



eMagin

# Materials for OLEDs

## Early OLED Structure (Kodak materials)



## Later developments

Polymers for transport  
and emission  
(arylamines, fluorenes, ...)

Crosslinkable polymers  
for multilayering

Polymeric anodes  
(polyaniline, polythiophene  
- PEDOT)

Emissive dyes  
(modification of laser dyes,  
use of triplet excitons)

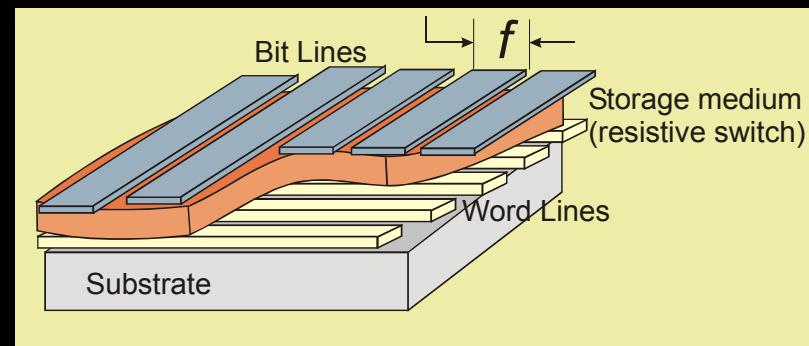
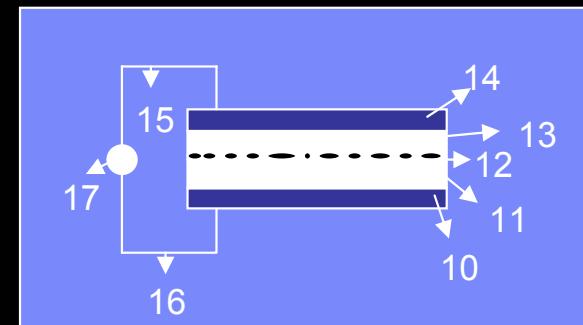
# Lessons from OLED

- A completely new technology
  - Not a replacement component
- Initial commercialization at the low end
  - Cell phones
  - Automotive (radio, navigation)
  - Small alphabetic displays
  - Cameras
  - Computer screens much later?
- Entrenched technologies generate \$ to improve
  - LCD viewing angle
  - LCD Efficiency / Brightness
  - Cost



# Nanotrap memory – nonvolatile, solid-state

- Metallic nanoparticles imbedded in organic semiconducting matrix
- Data stored as charges on nanoparticles
- Two-terminal bit-cell
- $4f^2$  in crosspoint architecture
- Thin film processing on flex substrate?

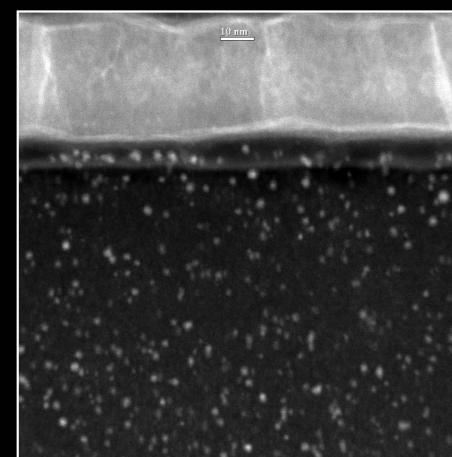
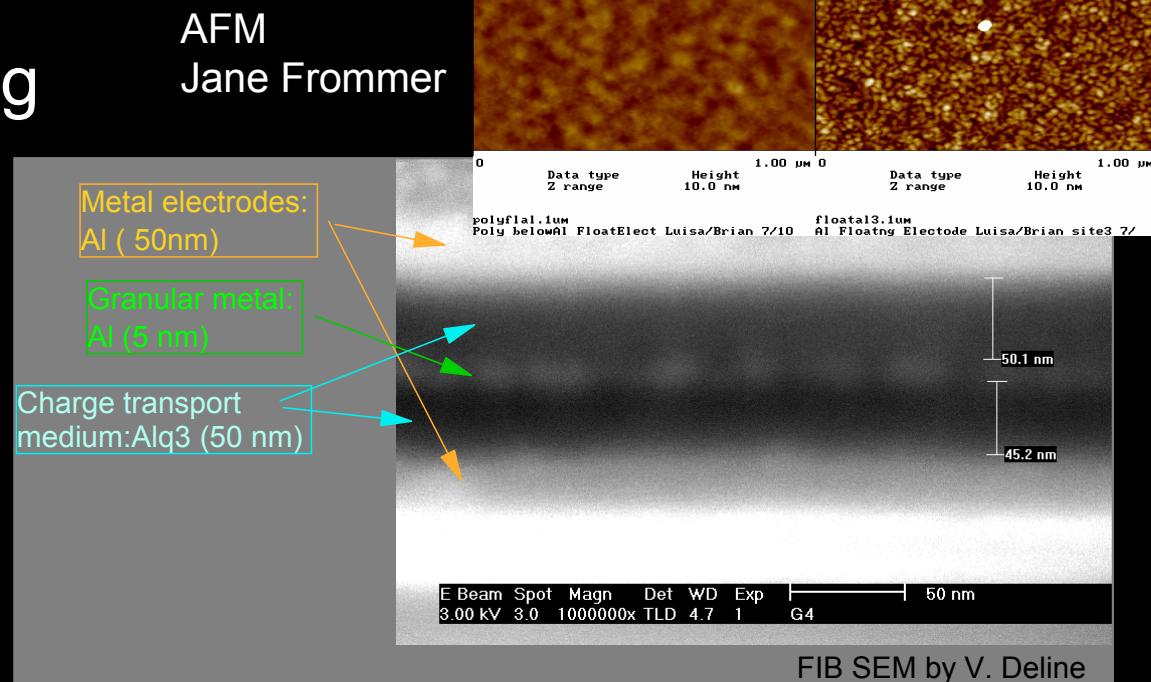


## Motivation

- Weaknesses of HDD
  - Reliability of moving parts
  - Long access times
  - High standby power
  - Poor granularity (higher cost/GB at lower capacity)
- Weaknesses of Flash
  - Relatively low endurance ( $10^5$  –  $10^6$  write/erase cycles)
  - Long write times (2 ms erase,  $200\ \mu\text{s}$  write)
  - Scaling (45 nm or 32 nm?)

# Device structure

- Metallic nanoparticles imbedded in semiconducting host matrix
- Sandwich between metal electrodes
- Fabrication:
  1. Thermal evaporation  
Island growth of metallic layer
  2. Spin coating of polymer/NP blend  
NP ( $\sim 1 - 10$  nm) dispersed throughout polymer layer  
Multiple layers w/wo NP



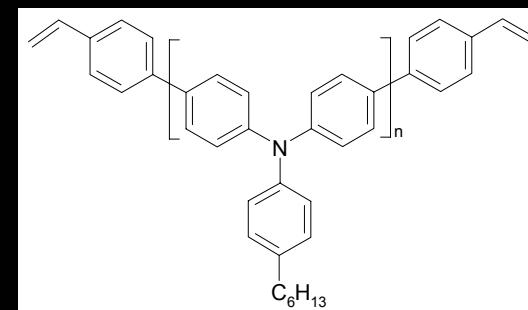
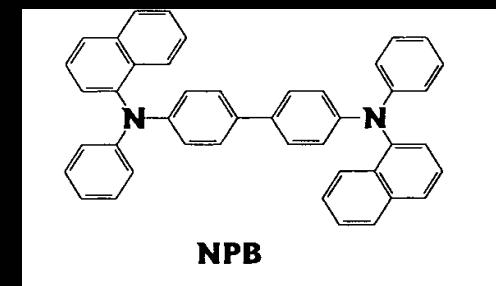
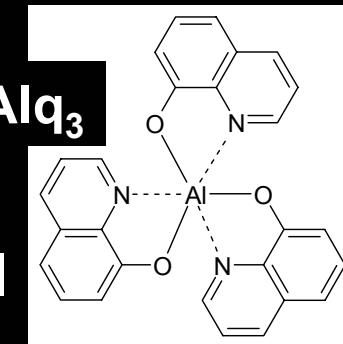
TEM  
Phil Rice

L. D. Bozano et al.  
*Appl. Phys Lett.*, 2004

# Materials

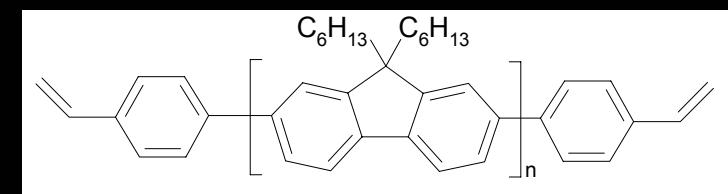
Semiconducting host

- Small Organic Molecule  
 $\text{Alq}_3$  - Electron transporting material
- NPB - Hole transporting material
- Wide bandgap inorganic  
 $\text{SiO}$ ,  $\text{ZnSe}$
- (X-linkable) Polymer  
 Arylamine - X-HTPA  
 Conjugated polyfluorene - X-DHF  
 Poly(biphenylmethylene) e.g. xBPF6



X-HTPA

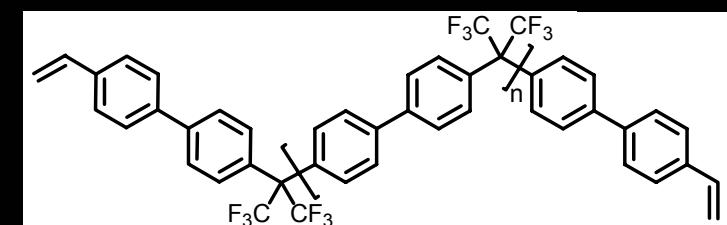
X-DHF



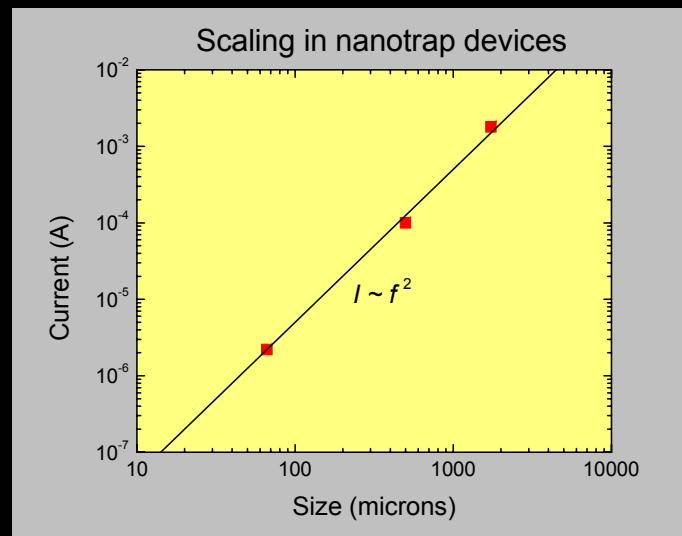
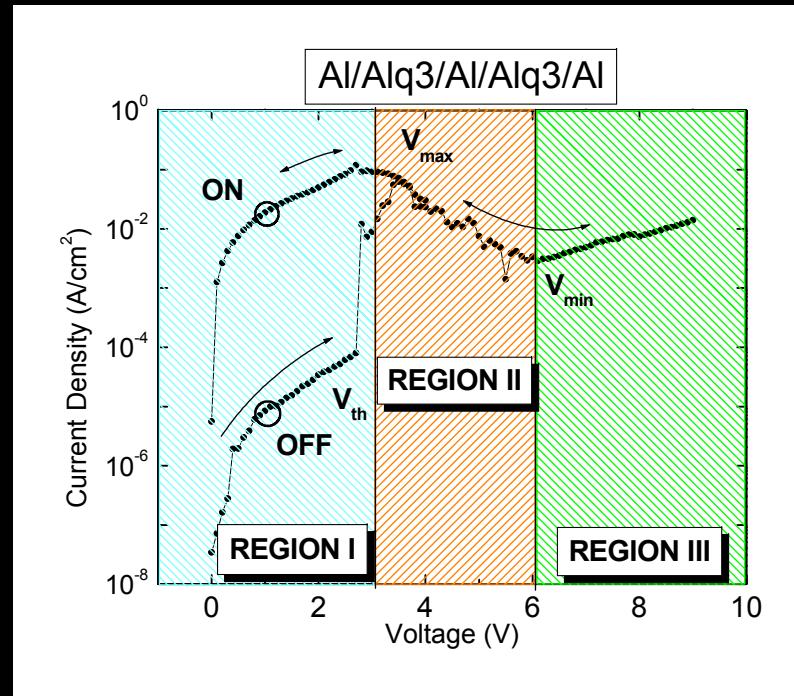
BPF6

Metal electrodes and NP

- NP: Au
- Evaporated islands: Cu, Cr, Al, Ag, Au, Mg
- Electrodes:  
 Anode: Au, Al, Ag, ITO, Cu, Cr, Ni  
 Cathode: Ca, Al, Cr, Au, Ag



# Features of dc electrical response



- "N-shaped" current-voltage  
Negative quadrant similar
- Region I  
 $V < V_{max} \sim V_{th}$  : bistable region,  
current depends on history
- Region II  
 $V_{max} < V < V_{min}$  : negative differential  
resistance, noisy, irreproducible
- Region III  
 $V_{min} < V$  : monotonic
- Turn on with pulse near  $V_{max}$   
Turn off with pulse near  $V_{min}$
- (On) Current scales with device area

# Nano-trap memory - Summary

## ■ Good

- On-off resistance ratio (  $> 100$  )
- Switching time (  $< 1 \mu\text{s}$  )
- Operating voltage (  $< 8 \text{ V}$  )
- Power consumption to switch (  $< 1 \mu\text{J/cm}^2$  )
- Understand basic mechanism

## ■ Promising

- Retention time (  $> 1 \text{ y}$  )
- Cycling endurance (  $> 10^4$  )
- On-state resistance, read time (high but getting lower)

## ■ Poor

- Rectification ratio (too low)

